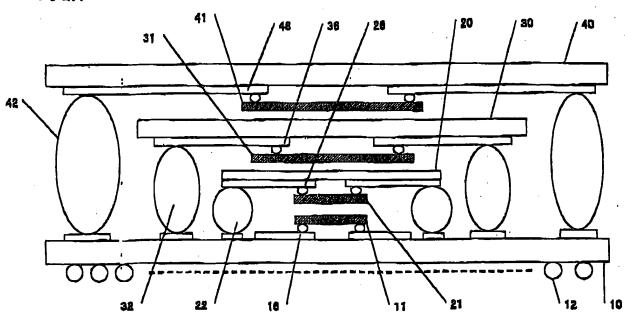
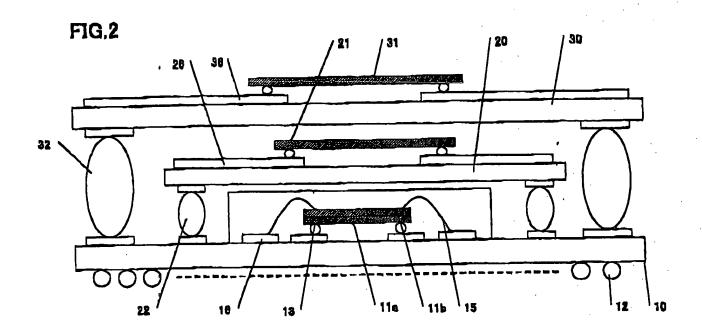
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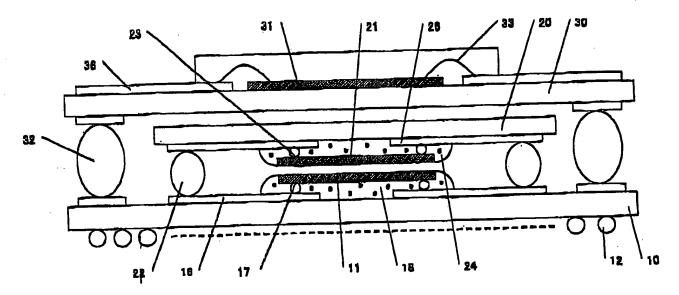
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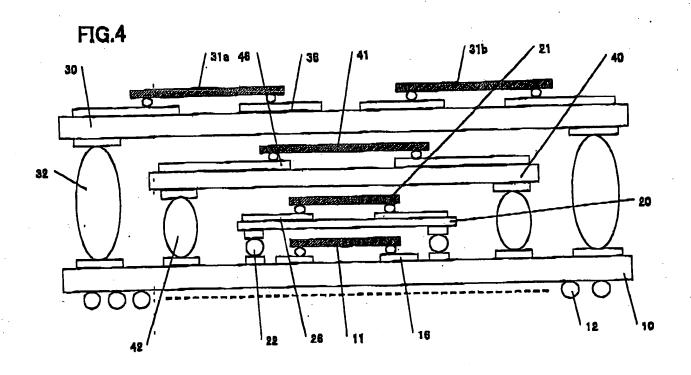
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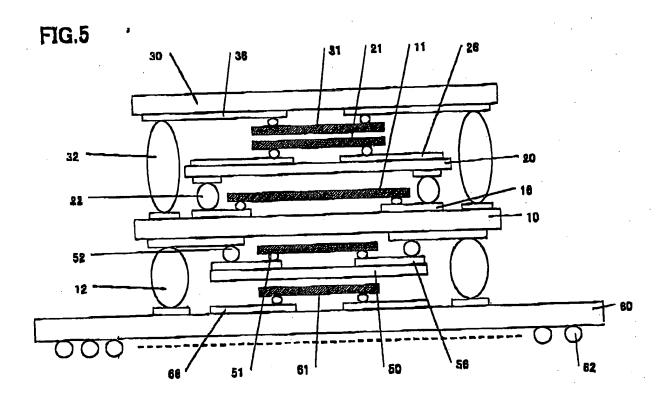
FIG.3



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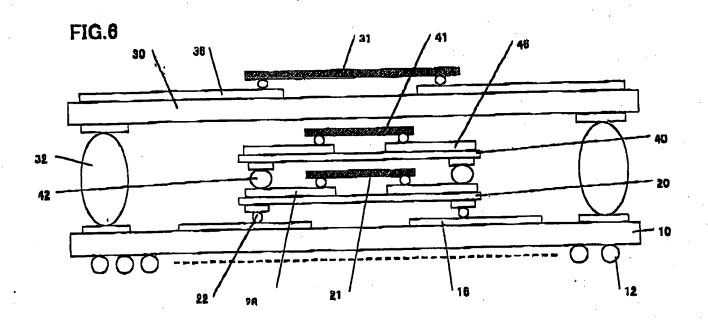


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Its Manufacturing Method and Electronic
Device"
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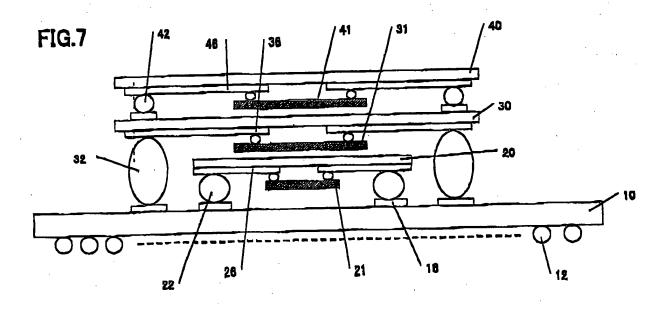


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